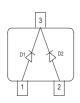


Silicon Variable Capacitance Diodes

- For FM radio tuners with extended frequency band
- High tuning ratio at low supply voltage (car radio)
- Monolithic chip (common cathode) for perfect dual diode tracking
- Coded capacitance groups and group matching available
- Pb-free (RoHS compliant) package



BB814

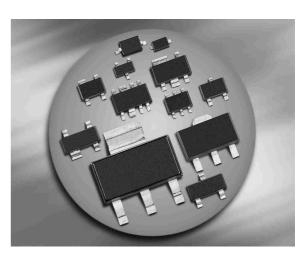


Туре	Package	Configuration	L_S (nH)	Marking
BB814	SOT23	common cathode	1.8	SH1/2*

*For differences see next page Capacitance groups

Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit	
Diode reverse voltage	V _R	18	V	
Peak reverse voltage-	V _{RM}	20		
Forward current	I _F	50	mA	
Operating temperature range	T _{op}	-55 125	°C	
Storage temperature	T _{sta}	-55 150		





Parameter	Symbol	Values			Unit
		min.	typ.	max.	1
DC Characteristics					
Reverse current	I _R				nA
<i>V</i> _R = 16 V		-	-	20	
<i>V</i> _R = 16 V, <i>T</i> _A = 60 °C		-	-	200	
AC Characteristics					
Diode capacitance ¹⁾	CT				pF
<i>V</i> _R = 2 V, <i>f</i> = 1 MHz		43	44.75	46.5	
V _R = 8 V, <i>f</i> = 1 MHz		19.1	20.8	22.7	
Capacitance ratio	C _{T2} /C _{T8}	2.05	2.15	2.25	
V _R = 2 V, V _R = 8 V, <i>f</i> = 1 MHz					
Capacitance matching ²⁾	∆C _T /C _T	-	-	3	%
$V_{\rm R}$ = 2 V, $V_{\rm R}$ = 8 V, f = 1 MHz					
Series resistance	r _S	-	0.18	-	Ω
V _R = 2 V, <i>f</i> = 100 MHz					
Q factor	Q	-	200	-	
<i>f</i> = 100 MHz, <i>V</i> _R = 2 V					

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

 $^{1}Capacitance groups at 2V and 8V, coded 1; 2 <math display="inline">C_{T}/groups$ 1 2

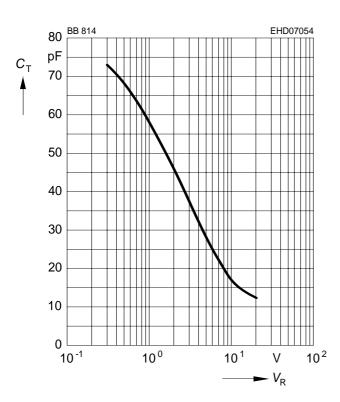
C _{2V}	min	43pF	44.5pF
C _{2V}	max	45pF	46.5pF
C _{8V}	min	19.1pF	19.75pF
C _{8V}	max	21.95pF	22.7pF

²For details please refer to Application Note 047.



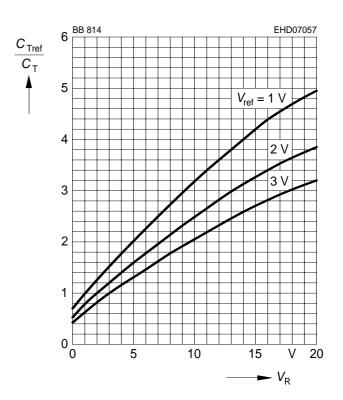
Diode capacitance $C_{T} = f(V_{R})$

f = 1MHz

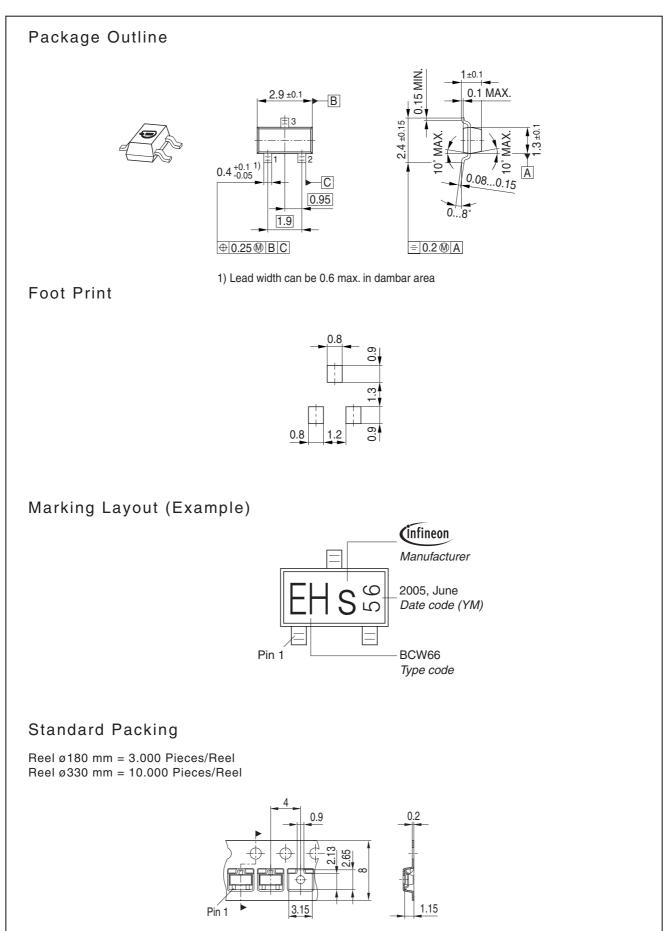


Capacitance ratio $C_{\text{Tref}}/C_{\text{T}} = f(V_{\text{R}})$

f = 1 MHz









Edition 2009-11-16

Published by Infineon Technologies AG 81726 Munich, Germany

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